NSN 5961-01-081-3429

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View Online at https://aerobasegroup.com/nsn/5961-01-081-3429 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 drain to source voltage and 15.0 gate to source voltage **Current Rating Per Characteristic:** 2.00 amperes drain current **Power Rating Per Characteristic:** 25.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:** 80131-release6675 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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